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Fast Soft Recovery Rectifier Diode, 20 A



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TO-220 FullPAK 2L

PRIMARY CHARACTERISTICS					
I _{F(AV)}	20 A				
V _R	200 V, 400 V, 600 V				
V _F at I _F	1.3 V				
I _{FSM}	300 A				
t _{rr}	60 ns				
T _J max.	150 °C				
Snap factor	0.6				
Package	TO-220 FullPAK 2L				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operation junction temperature
 Designed and qualified according to JEDEC[®]-JESD 47



FREE

- Fully isolated package (V_{INS} = 2500 V_{RMS})
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-20ETF0..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Sinusoidal waveform	20	A					
V _{RRM}		200 to 600	V					
I _{FSM}		300	А					
V _F	10 A, T _J = 25 °C	1.2	V					
t _{rr}	1 A, 100 A/μs	60	ns					
TJ		-40 to +150	°C					

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-20ETF02FP-M3	200	300					
VS-20ETF04FP-M3	400	500	5				
VS-20ETF06FP-M3	600	700					

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	$T_C = 51 \text{ °C}$, 180° conduction half sine wave	20			
Maximum peak one cycle non-repetitive	I _{FSM}	10 ms sine pulse, rated V_{RRM} applied	250	A		
surge current		10 ms sine pulse, no voltage reapplied	300			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	316	A ² s		
Maximum - t for fusing		10 ms sine pulse, no voltage reapplied	442	A-5		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s		

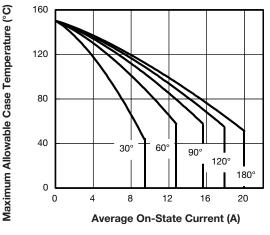
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A, T _J = 25 °C		1.30	V	
Maximum forward voltage drop	V _{FM}	60 A, T _J = 25 °C 1.67		1.67	v	
Forward slope resistance	r _t	T _J = 150 °C		12.5	mΩ	
Threshold voltage	V _{F(TO)}	T _J = 150 °C		0.9	V	
Maximum reverse leakage current	1	T _J = 25 °C	V Pated V	0.1	mA	
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	$V_R = Rated V_{RRM}$	5.0	ША	

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	†		
Reverse recovery time	t _{rr}	I _F at 20 A _{pk}	160	ns	I _{FM}		
Reverse recovery current	I _{rr}	100 A/µs	10	А	1		
Reverse recovery charge	Q _{rr}	25 °C	1.25	μC			
Snap factor	S	Typical	0.6		I I I I I I I I I I I I I I I I I I I		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range			-40 to +150	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.5		
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.5		
Approximate weight				2	g	
				0.07	oz.	
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm	
				12 (10)	(lbf · in)	
Marking device			Case style TO-220 FullPAK 2L	20ETI	F02FP F04FP F06FP	

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Fig. 1 - Current Rating Characteristics

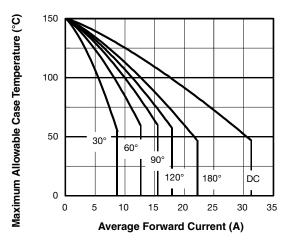


Fig. 2 - Current Rating Characteristics

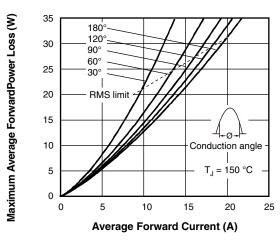


Fig. 3 - Forward Power Loss Characteristics

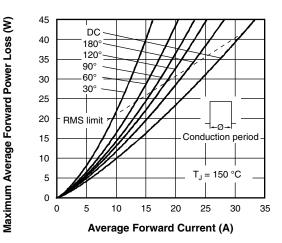
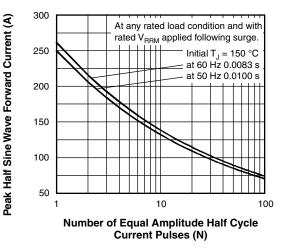


Fig. 4 - Forward Power Loss Characteristics





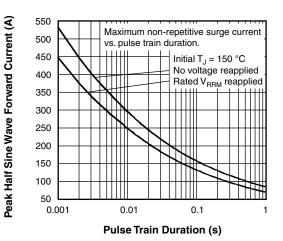


Fig. 6 - Maximum Non-Repetitive Surge Current

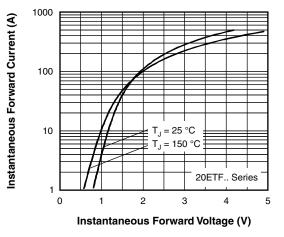
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Fig. 7 - Forward Voltage Drop Characteristics

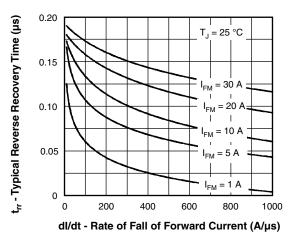


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \ ^{\circ}C$

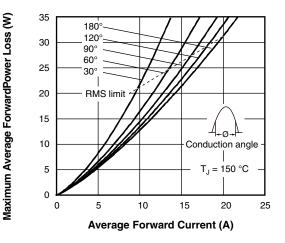


Fig. 9 - Recovery Time Characteristics, $T_J = 150$ °C

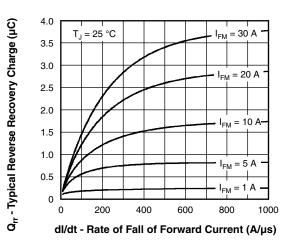


Fig. 10 - Recovery Charge Characteristics, $T_J = 25 \ ^{\circ}C$

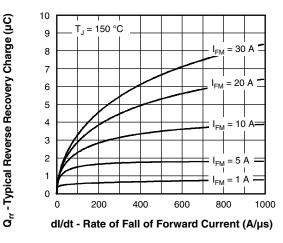


Fig. 11 - Recovery Charge Characteristics, $T_J = 150 \ ^\circ C$

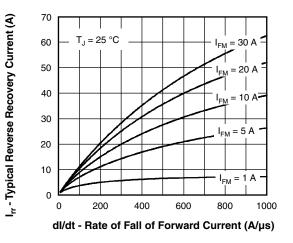


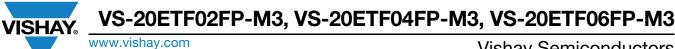
Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

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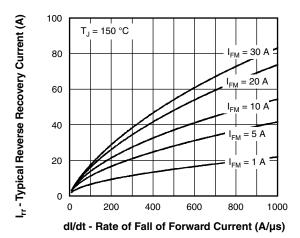


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

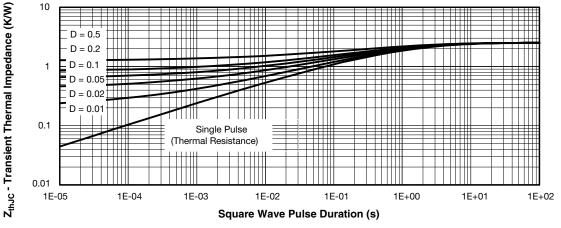


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

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Device code	VS-	20	Е	т	F	06	FP	-M3
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
	1 -	. Visl	hav Sen	niconduo	ctors pro	oduct		
	2 -		-	ng (20 =	-			
	3 -	- Circ	uit conf	iguratio	า:			
		E =	single c	liode				
	4	- Pac	kage:					
		T =	TO-220	1				
	5 -	- Тур	e of silio	con:				
		F =	fast sof	t recove	ry rectif	ier	02 = 2	200 V
	6 -	- Vol	age coo	de x 100	= V _{RRN}	1		400 V
	7 -	· Full	PAK				06 = 0	600 V
	8 -	- Env	rironmer	ntal digit	:			
		-M	3 = halo	gen-free	e, RoHS	-compli	ant, and	d termir

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-20ETF02FP-M3	50	1000	Antistatic plastic tubes				
VS-20ETF04FP-M3	50	1000	Antistatic plastic tubes				
VS-20ETF06FP-M3	50	1000	Antistatic plastic tubes				

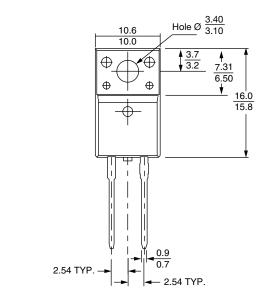
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96157				
Part marking information	www.vishay.com/doc?95392				
SPICE model	www.vishay.com/doc?95410				

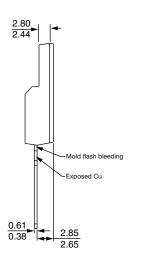


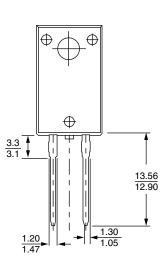
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2L TO-220 FullPAK

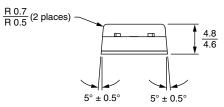
DIMENSIONS in millimeters







Bottom view





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